

Features

- Frequency: 0.9~1.3GHz
- Gain: 20.2dB
- Output P_{-1dB}: 26.4dBm
- Supply Voltage: +5V@265mA
- Die Size: 1.1mm×1.25mm×0.1mm

Typical Applications

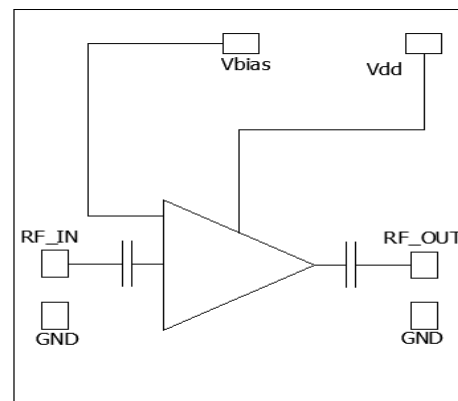
- EW
- Cellular Infrastructure
- SATCOM
- Beamforming Modules
- Test Equipment and Sensors

General Description

XT3901 is a GaAs MMIC driver amplifier which operates between 0.9GHz~1.3GHz. The amplifier provides 20.2dB of gain, 26.4dBm Output P_{-1dB} power and 3.8dB noise figure while requiring 265mA from a +5V supply voltage.

The chip offers full passivation for increased reliability and moisture protection. This amplifier is the perfect alternative to higher cost hybrid amplifiers.

Functional Diagram



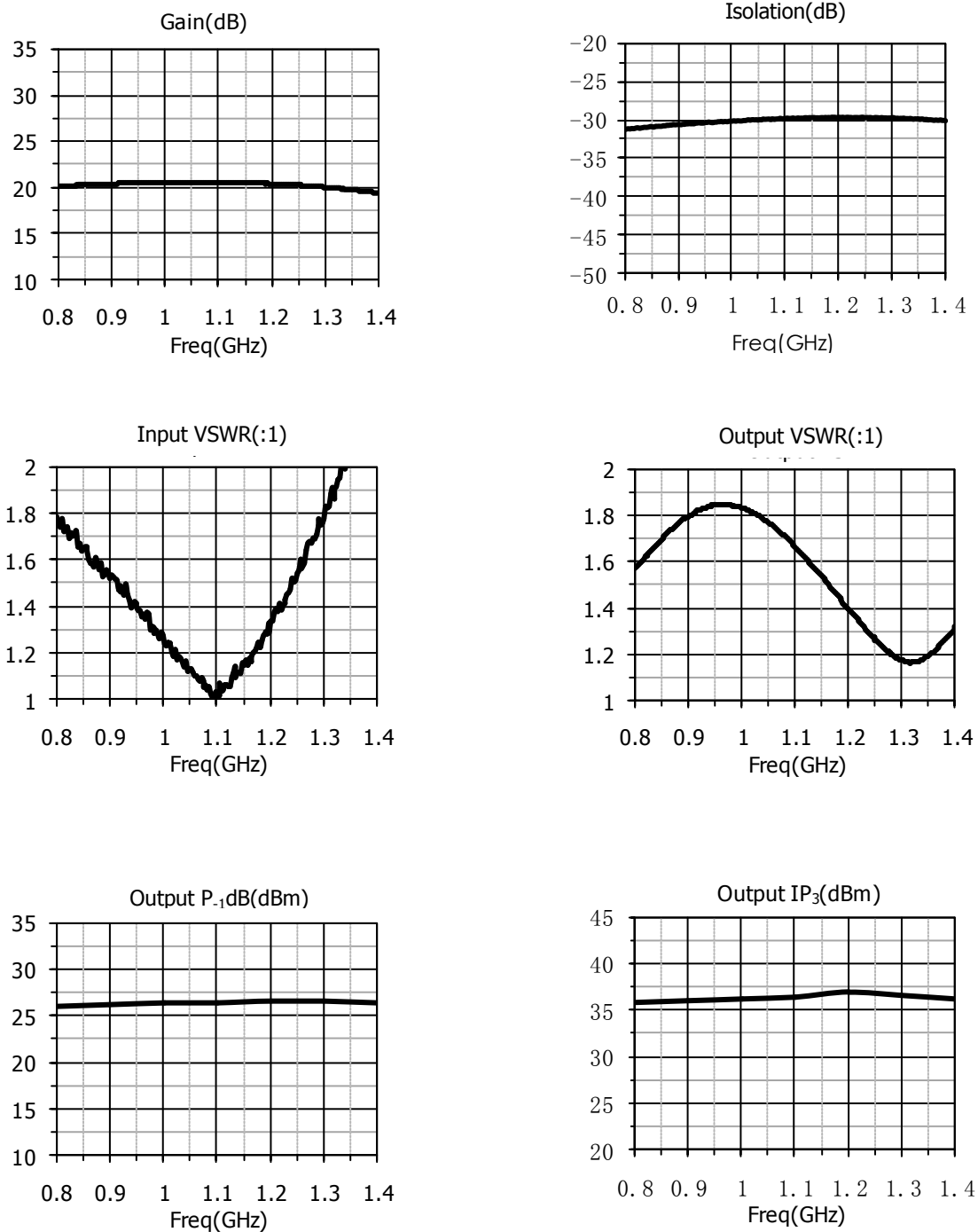
Electrical Performance (T_A=25°C,V_D=+5V,I_D=265mA,Z₀=50Ω)

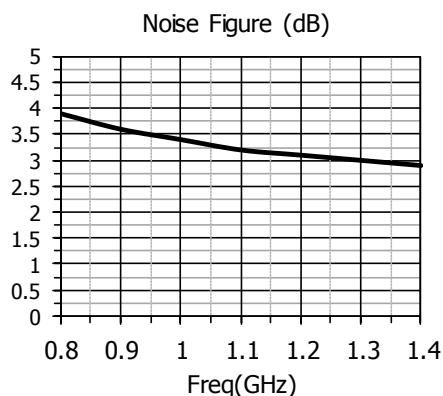
Parameter	Min.	Typ.	Max.	Units
Frequency Range	0.9~1.3			GHz
Small Signal Gain	—	20.2	—	dB
Small Signal Gain Flatness	—	0.6	—	dB
Reverse Isolation	—	-30	—	dB
Input/Output VSWR	—	1.8	—	:1
Noise Figure	—	3.8	—	dB
Output Power for 1 dB Compression (OP _{-1dB})	—	26.4	—	dBm
Output Third Order Intercept (OIP ₃)	—	36.5	—	dBm
Supply Current(I _D)	—	265	—	mA

Absolute Maximum Ratings

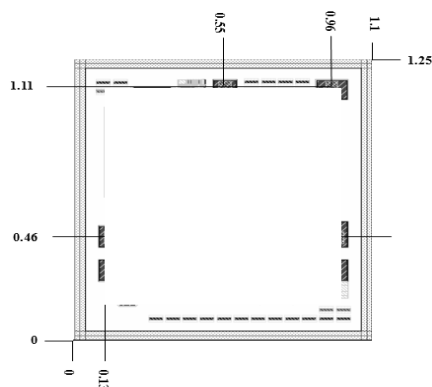
Maximum Input Power	+18dBm	Operating Temperature	-55°C ~+85°C
Channel temperature	150°C	Storage Temperature	-65°C ~+150°C

Typical Performance Curve

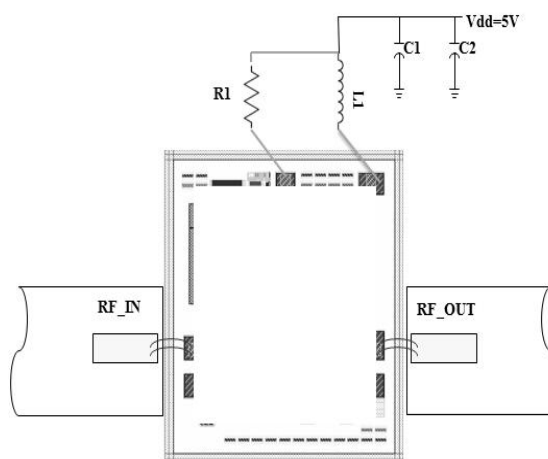




Die Outline
(all dimensions in mm)



Assembly Diagram



Component list

Reference Des.	Value	Part Number	Manuf.	Size
R1	200Ω	—	—	0603
C1	10nF	GRM1857U1A103JA44	MURATA	0603
C2	1uF	GRM188R60J105KA01	MURATA	0603
L1	8.2nH	0603LS8N2XJLC	COILCRAFT	0603

Attention:

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.